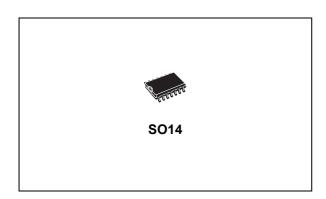


Hex inverter

Datasheet - production data



Features

- Medium-speed operation t_{PD} = 30 ns (typ.) at 10 V
- Standardized symmetrical output characteristics
- Quiescent current specified up to 20 V
- 5 V, 10 V, and 15 V parametric ratings
- Input leakage current I_I = 100 nA (max.) at V_{DD} = 18 V and T_A = 25 °C
- 100 % tested for quiescent current

ESD performance

HBM: 1 kVMM: 200 VCDM: 1 kV

Applications

- Automotive
- Industrial
- Computer
- Consumer

Description

The HCF4069U is a monolithic integrated circuit fabricated in metal oxide semiconductor technology available in the SO14 package. The HCF4069U consists of six COS/MOS inverter circuits. This device is intended for all general purpose inverter applications where the medium power TTL-drive and logic level conversion capabilities of circuits such as HCF4049 hex inverter/buffers are not required.

Table 1. Device summary table

Order code	Temperature range	Package	Packing	Marking
HCF4069UM013TR	-55 ° C to +125 ° C	SO14		HCF4069U
HCF4069YUM013TR (1)	-40 ° C to +125 ° C	SO14 (automotive grade) ⁽¹⁾	Tape and reel	HCF4069Y

Qualification and characterization according to AEC Q100 and Q003 or equivalent, advanced screening according to AEC Q001 & Q002 or equivalent.

Contents HCF4069U

Contents

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4	Package information
3	Electrical characteristics
2	Functional description
1	Pin information

HCF4069U Pin information

1 Pin information

Figure 1. Pin connections (top view)

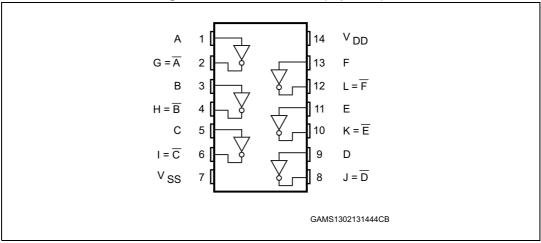


Table 2. Pin description

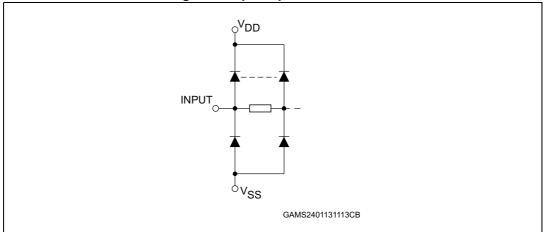
Pin no	Symbol	Name and function
1, 3, 5, 9, 11, 13	A, B, C, D, E, F	Data inputs
2, 4, 6, 8, 10, 12 G, H, I, J, K, L Data out		Data outputs
7	V _{SS}	Negative supply voltage
14	V_{DD}	Positive supply voltage

2 Functional description

Table 3. Truth table

Inputs	Outputs
A, B, C, D, E, F	G, H, I, J, K, L
L	Н
Н	L

Figure 2. Input equivalent circuit



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3 Electrical characteristics

Absolute maximum ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied. All voltage values are referred to V_{SS} pin voltage.

Table 4. Absolute maximum ratings (AMR)

Symbol	Parameter	Value	Unit
V_{DD}	Supply voltage	-0.5 to +22	V
V _I	DC input voltage	-0.5 to V _{DD} + 0.5	V
l _l	DC input current	±10	mA
D	Power dissipation per package	200	mW
P_{D}	Power dissipation per output transistor	100	IIIVV
T _{op}	Operating temperature	-55 to +125	°C
T _{stg}	Storage temperature	-65 to +150	

Table 5. Recommended operating conditions

Symbol	Parameter	Value	Unit
V_{DD}	Supply voltage	3 to 20	V
V _I	Input voltage	0 to V _{DD}	V
T _{op}	Operating temperature	-55 to 125	°C

Electrical characteristics HCF4069U

Table 6. DC specifications⁽¹⁾

			Test c	ondition					Value)			
Sym.	Parameter	V 00	V 00	II 1 (A)	V 00	Τ _Δ	= 25 °	С	-40 to	85 °C	-55 to	125 °C	Unit
		V _I (V)	V _O (V)	I_O (μA)	V _{DD} (V)	Min.	Тур.	Max.	Min.	Max.	Min.	Max.	
		0/5			5			0.25		7.5		7.5	
	Quiescent	0/10			10		0.01	0.5		15		15	
ΙL	current	0/15			15			1		30		30	μΑ
		0/20			20		0.02	5		150		150	
	High level	0/5			5	4.95			4.95		4.95		
V _{OH}	output	0/10		<1	10	9.95			9.95		9.95		
	voltage	0/15			15	14.95			14.95		14.95		
	Low level	5/0			5								
V _{OL}	output	10/0		<1	10		0.05			0.05		0.05	
	voltage	15/0			15								.,
	High level		0.5/4.5		5	4			4		4		V
V _{IH}	input		1/9	<1	10	8			8		8		
	voltage		1.5/13.5		15	12.5			12.5		12.5		
	Low level		4.5/0.5		5			1		1		1	
V _{IL}	input		9/1	<1	10			2		2		2	
	voltage		13.5/1.5		15			2.5		2.5		2.5	
		0/5	2.5		_	-1.36	-3.2		-1.15		-1.1		
	Output drive	0/5	4.6	-1	5	-0.44	-1		-0.36		-0.36		
I _{OH}	current	0/10	9.5	<1	10	-1.1	-2.6		-0.9		-0.9		
		0/15	13.5		15	-3.0	-6.8		-2.4		-2.4		mA
		0/5	0.4		5	0.44	1		0.36		0.36		
I _{OL}	Output sink current	0/10	0.5	<1	10	1.1	2.6		0.9		0.9		
	Sarront	0/15	1.5	1.5	15	3.0	6.8		2.4		2.4		
I	Input leakage current	0/18	Any	input	18		±10 ⁻⁵	±0.1		±1		±1	μА
C _I	Input capacitance		Any	input			5	7.5					pF

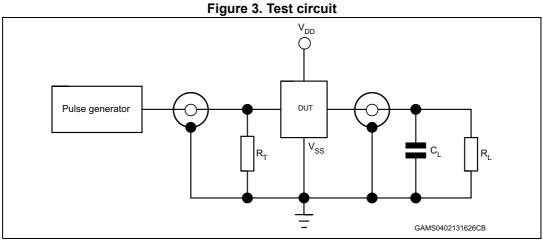
^{1.} The noise margin for both level "1" and "0" is: 1 V min. with $V_{DD} = 5$ V, 2 V min. with $V_{DD} = 10$ V, and 2.5 V min. with $V_{DD} = 15$ V.



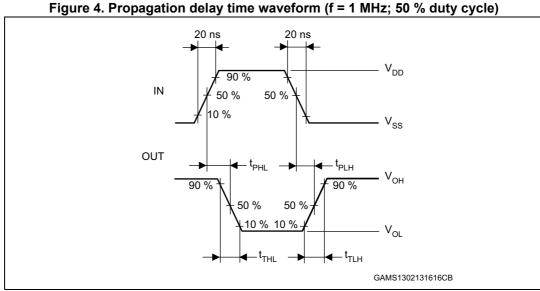
Symbol	Parameter	Test condition	Valu	Unit	
	Farameter	V _{DD} (V)	Тур.	Max.	Oill
t _{PLH} , t _{PHL} Pro	Propagation delay time	5	55	110	
		10	30	60	
		15	25	50	no
		5	100	200	ns
t _{TLH} , t _{THL}	Output transition time	10	50	100	
		15	40	80	1

Table 7. Dynamic electrical characteristics $(T_{amb} = 25 \text{ °C}, C_L = 50 \text{ pF}, R_L = 200 \text{ k}\Omega, t_r = t_f = 20 \text{ ns})$

^{1.} The typical temperature coefficient for all $\rm V_{DD}$ values is 0.3 $\rm \%/^{\circ}C.$



1. Legend: C_L = 50 pF or equivalent (includes jig and probe capacitance), R_L = 200 K Ω , R_T = Z_{OUT} of pulse generator (typically 50 Ω)



Package information HCF4069U

4 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.



4.1 SO14 package information

Figure 5. SO14 package mechanical drawing

Table 8. SO14 package mechanical data

	Dimensions							
Ref	Millimeters				Inches	Inches		
	Min.	Тур.	Max.	Min.	Тур.	Max.		
Α			1.75			0.068		
a1	0.1		0.2	0.003		0.007		
a2			1.65			0.064		
b	0.35		0.46	0.013		0.018		
b1	0.19		0.25	0.007		0.010		
С		0.5			0.019			
c1		45 °			45 °			
D	8.55		8.75	0.336		0.344		
Е	5.8		6.2	0.228		0.244		
е		1.27			0.050			
e3		7.62			0.300			
F	3.8		4.0	0.149		0.157		
G	4.6		5.3	0.181		0.208		
L	0.5		1.27	0.019		0.050		
М			0.68			0.026		
S			8 °			8 °		

Ordering information HCF4069U

5 Ordering information

Table 9. Order codes

Order code	Temp. range	Package	Packing	Marking
HCF4069UM013TR	-55 ° C to +125 ° C	SO14	Tape and	HCF4069U
HCF4069YUM013TR (1)	-40 ° C to +125 ° C	SO14 (automotive grade) ⁽¹⁾	reel	HCF4069Y

Qualification and characterization according to AEC Q100 and Q003 or equivalent, advanced screening according to AEC Q001 & Q002 or equivalent.

6 Revision history

Table 10. Document revision history

Date	Revision	Changes
18-Feb-2013	4	Document template and layout updated Removed "B" from part number. Updated package names (PDIP-14 and SO14 instead of DIP-14 and SOP-14). Added Applications. Added Device summary table. Added Section 5: Ordering information.
22-Mar-2013	5	Updated Table 1: Device summary table and Table 9: Order codes.
10-Jan-2014	6	Removed PDIP-14 package Added ESD data to Features Table 1: Device summary table: updated footnote 1. Table 9: Order codes: updated footnote 1.

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